



# 2PA1774xMB series

40 V, 100 mA PNP general-purpose transistors

Rev. 1 — 23 March 2012

Product data sheet

## 1. Product profile

### 1.1 General description

PNP general-purpose transistors in a leadless ultra small DFN1006B-3 (SOT883B) Surface-Mounted Device (SMD) plastic package.

Table 1. Product overview

| Type number | Package |       |       | NPN complement |
|-------------|---------|-------|-------|----------------|
|             | NXP     | JEITA | JEDEC |                |
| 2PA1774QMB  | SOT883B | -     | -     | 2PC4617QMB     |
| 2PA1774RMB  | SOT883B | -     | -     | 2PC4617RMB     |
| 2PA1774SMB  | SOT883B | -     | -     | -              |

### 1.2 Features and benefits

- Leadless ultra small SMD plastic package
- Low package height of 0.37 mm
- Power dissipation comparable to SOT23
- AEC-Q101 qualified

### 1.3 Applications

- General-purpose switching and amplification
- Mobile applications

### 1.4 Quick reference data

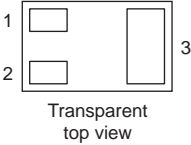
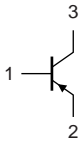
Table 2. Quick reference data

| Symbol    | Parameter                 | Conditions                                 | Min | Typ | Max  | Unit |
|-----------|---------------------------|--|-----|-----|------|------|
| $V_{CE0}$ | collector-emitter voltage | open base                                  | -   | -   | -40  | V    |
| $I_C$     | collector current         |  | -   | -   | -100 | mA   |
| $h_{FE}$  | DC current gain           | $V_{CE} = -6\text{ V}; I_C = -1\text{ mA}$ |     |     |      |      |
|           | 2PA1774QMB                |  | 120 | -   | 270  |      |
|           | 2PA1774RMB                |  | 180 | -   | 390  |      |
|           | 2PA1774SMB                |  | 270 | -   | 560  |      |



## 2. Pinning information

Table 3. Pinning

| Pin | Description | Simplified outline  | Graphic symbol  |
|-----|-------------|---|---|
| 1   | base        |  <p>Transparent top view</p> |  <p>sym013</p> |
| 2   | emitter     |   |   |
| 3   | collector   |   |   |

## 3. Ordering information

Table 4. Ordering information

| Type number       | Package    |  |         |
|-------------------|------------|--|---------|
|                   | Name       | Description  | Version |
| 2PA1774xMB series | DFN1006B-3 | leadless ultra small plastic package; 3 solder lands; body 1.0 × 0.6 × 0.37 mm | SOT883B |

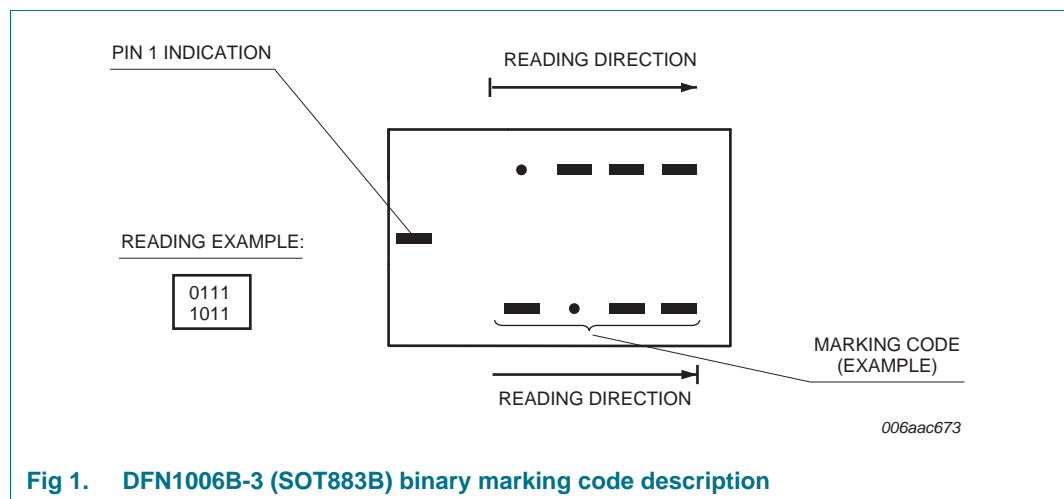
## 4. Marking

Table 5. Marking codes

| Type number | Marking code <sup>[1]</sup> |
|-------------|-----------------------------|
| 2PA1774QMB  | 0100 0000                   |
| 2PA1774RMB  | 0000 1101                   |
| 2PA1774SMB  | 0000 1110                   |

[1] For DFN1006B-3 (SOT883B) binary marking code description see [Figure 1](#).

### 4.1 Binary marking code description



## 5. Limiting values

**Table 6. Limiting values**

*In accordance with the Absolute Maximum Rating System (IEC 60134).*

| Symbol    | Parameter                 | Conditions                       | Min    | Max  | Unit |    |
|-----------|---------------------------|----------------------------------|--------|------|------|----|
| $V_{CBO}$ | collector-base voltage    | open emitter                     | -      | -50  | V    |    |
| $V_{CEO}$ | collector-emitter voltage | open base                        | -      | -40  | V    |    |
| $V_{EBO}$ | emitter-base voltage      | open collector                   | -      | -5   | V    |    |
| $I_C$     | collector current         |                                  | -      | -100 | mA   |    |
| $I_{CM}$  | peak collector current    | single pulse;<br>$t_p \leq 1$ ms | -      | -200 | mA   |    |
| $I_{BM}$  | peak base current         | single pulse;<br>$t_p \leq 1$ ms | -      | -100 | mA   |    |
| $P_{tot}$ | total power dissipation   | $T_{amb} \leq 25$ °C             | [1][2] | -    | 250  | mW |
|           |                           |                                  | [3][2] | -    | 590  | mW |
| $T_j$     | junction temperature      |                                  | -      | 150  | °C   |    |
| $T_{amb}$ | ambient temperature       |                                  | -55    | +150 | °C   |    |
| $T_{stg}$ | storage temperature       |                                  | -65    | +150 | °C   |    |

[1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and standard footprint.

[2] Reflow soldering is the only recommended soldering method.

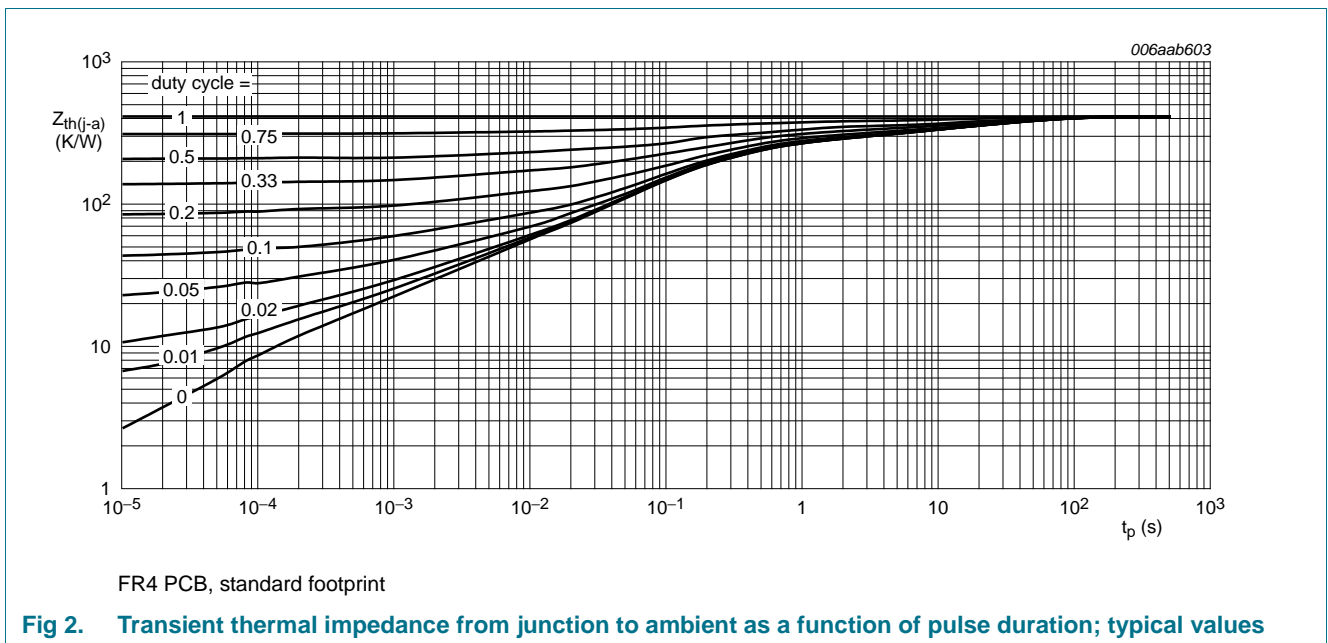
[3] Device mounted on an FR4 PCB, single-sided copper, mounting pad for collector 1 cm<sup>2</sup>.

6. Thermal characteristics

Table 7. Thermal characteristics

| Symbol        | Parameter                                   | Conditions  | Min    | Typ | Max | Unit |     |
|---------------|---|-------------|--------|-----|-----|------|-----|
| $R_{th(j-a)}$ | thermal resistance from junction to ambient | in free air | [1][2] | -   | -   | 500  | K/W |
|               |   |             | [3][2] | -   | -   | 212  | K/W |

- [1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.
- [2] Reflow soldering is the only recommended soldering method.
- [3] Device mounted on an FR4 PCB, single-sided copper, mounting pad for collector 1 cm<sup>2</sup>.



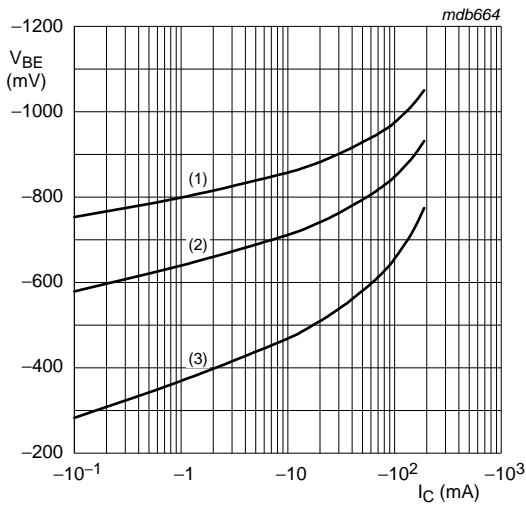
## 7. Characteristics

**Table 8. Characteristics**

$T_{amb} = 25\text{ }^{\circ}\text{C}$  unless otherwise specified.

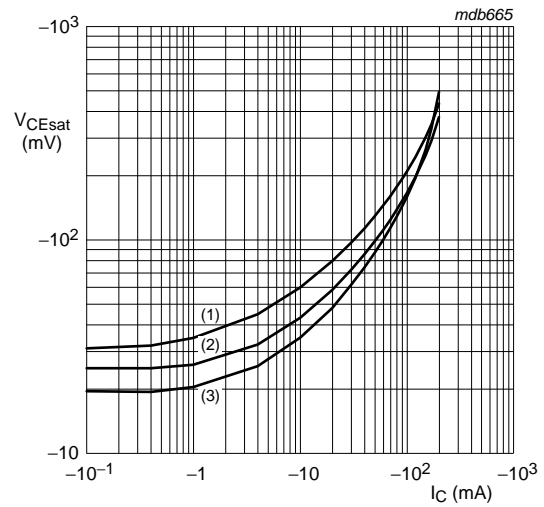
| Symbol      | Parameter                            | Conditions   | Min | Typ | Max  | Unit          |            |     |   |     |
|-------------|--------------------------------------|--|-----|-----|------|---------------|------------|-----|---|-----|
| $I_{CBO}$   | collector-base cut-off current       | $V_{CB} = -30\text{ V}; I_E = 0\text{ A}$                                    | -   | -   | -100 | nA            |            |     |   |     |
|             |                                      | $V_{CB} = -30\text{ V}; I_E = 0\text{ A}; T_j = 150\text{ }^{\circ}\text{C}$ | -   | -   | -5   | $\mu\text{A}$ |            |     |   |     |
| $I_{EBO}$   | emitter-base cut-off current         | $V_{EB} = -4\text{ V}; I_C = 0\text{ A}$                                     | -   | -   | -100 | nA            |            |     |   |     |
| $h_{FE}$    | DC current gain                      | $V_{CE} = -6\text{ V}; I_C = -1\text{ mA}$                                   |     |     |      |               |            |     |   |     |
|             |                                      |  |     |     |      |               | 2PA1774QMB | 120 | - | 270 |
|             |                                      |  |     |     |      |               | 2PA1774RMB | 180 | - | 390 |
|             |                                      |  |     |     |      |               | 2PA1774SMB | 270 | - | 560 |
| $V_{CEsat}$ | collector-emitter saturation voltage | $I_C = -50\text{ mA}; I_B = -5\text{ mA}$                                    | [1] | -   | -200 | mV            |            |     |   |     |
| $f_T$       | transition frequency                 | $V_{CE} = -12\text{ V}; I_C = -2\text{ mA}; f = 100\text{ MHz}$              | 100 | -   | -    | MHz           |            |     |   |     |
| $C_c$       | collector capacitance                | $V_{CB} = -12\text{ V}; I_E = I_e = 0\text{ A}; f = 1\text{ MHz}$            | -   | -   | 2.2  | pF            |            |     |   |     |

[1] Pulse test:  $t_p \leq 300\text{ }\mu\text{s}; \delta \leq 0.02$ .



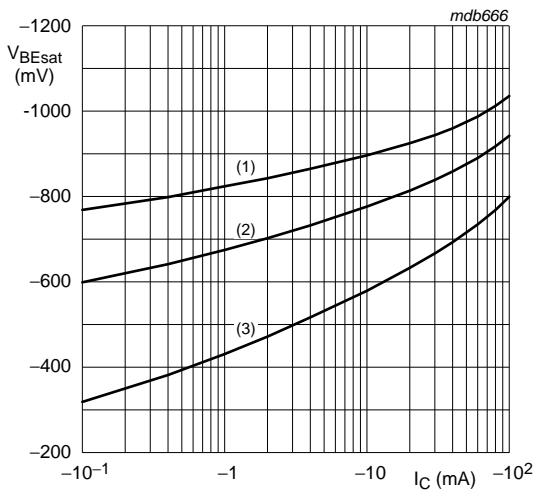
- $V_{CE} = -6\text{ V}$
- (1)  $T_{amb} = -55\text{ }^\circ\text{C}$
  - (2)  $T_{amb} = 25\text{ }^\circ\text{C}$
  - (3)  $T_{amb} = 150\text{ }^\circ\text{C}$

Fig 3. Base-emitter voltage as a function of collector current; typical values



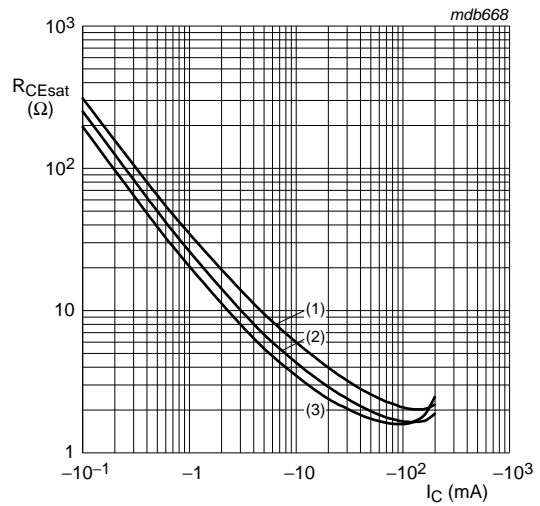
- $I_C/I_B = 10$
- (1)  $T_{amb} = 150\text{ }^\circ\text{C}$
  - (2)  $T_{amb} = 25\text{ }^\circ\text{C}$
  - (3)  $T_{amb} = -55\text{ }^\circ\text{C}$

Fig 4. Collector-emitter saturation voltage as a function of collector current; typical values



- $I_C/I_B = 10$
- (1)  $T_{amb} = -55\text{ }^\circ\text{C}$
  - (2)  $T_{amb} = 25\text{ }^\circ\text{C}$
  - (3)  $T_{amb} = 150\text{ }^\circ\text{C}$

Fig 5. Base-emitter saturation voltage as a function of collector current; typical values



- $I_C/I_B = 10$
- (1)  $T_{amb} = 150\text{ }^\circ\text{C}$
  - (2)  $T_{amb} = 25\text{ }^\circ\text{C}$
  - (3)  $T_{amb} = -55\text{ }^\circ\text{C}$

Fig 6. Collector-emitter equivalent on-resistance as a function of collector current; typical values

## 8. Test information

### 8.1 Quality information

This product has been qualified in accordance with the Automotive Electronics Council (AEC) standard *Q101 - Stress test qualification for discrete semiconductors*, and is suitable for use in automotive applications.

## 9. Package outline

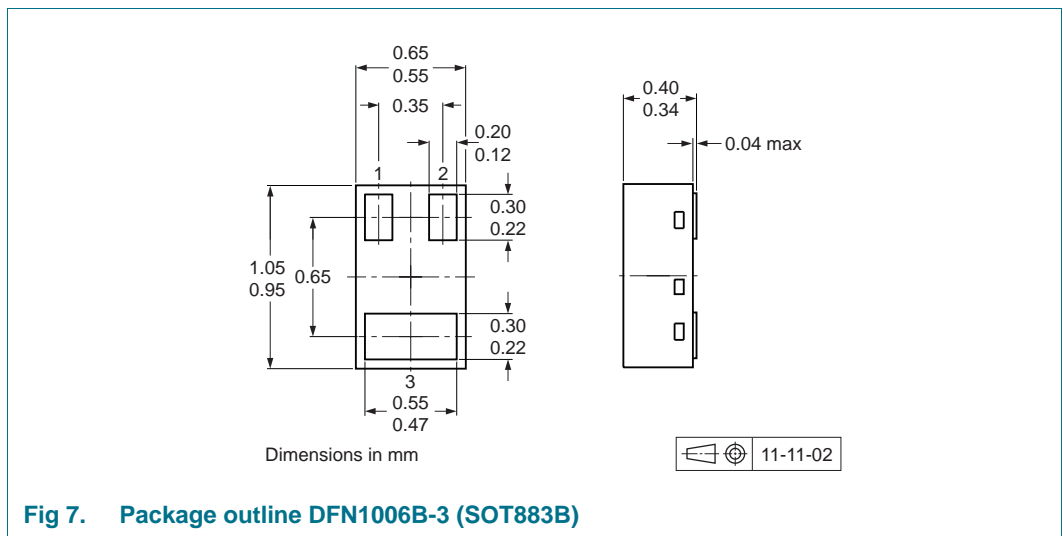


Fig 7. Package outline DFN1006B-3 (SOT883B)

## 10. Packing information

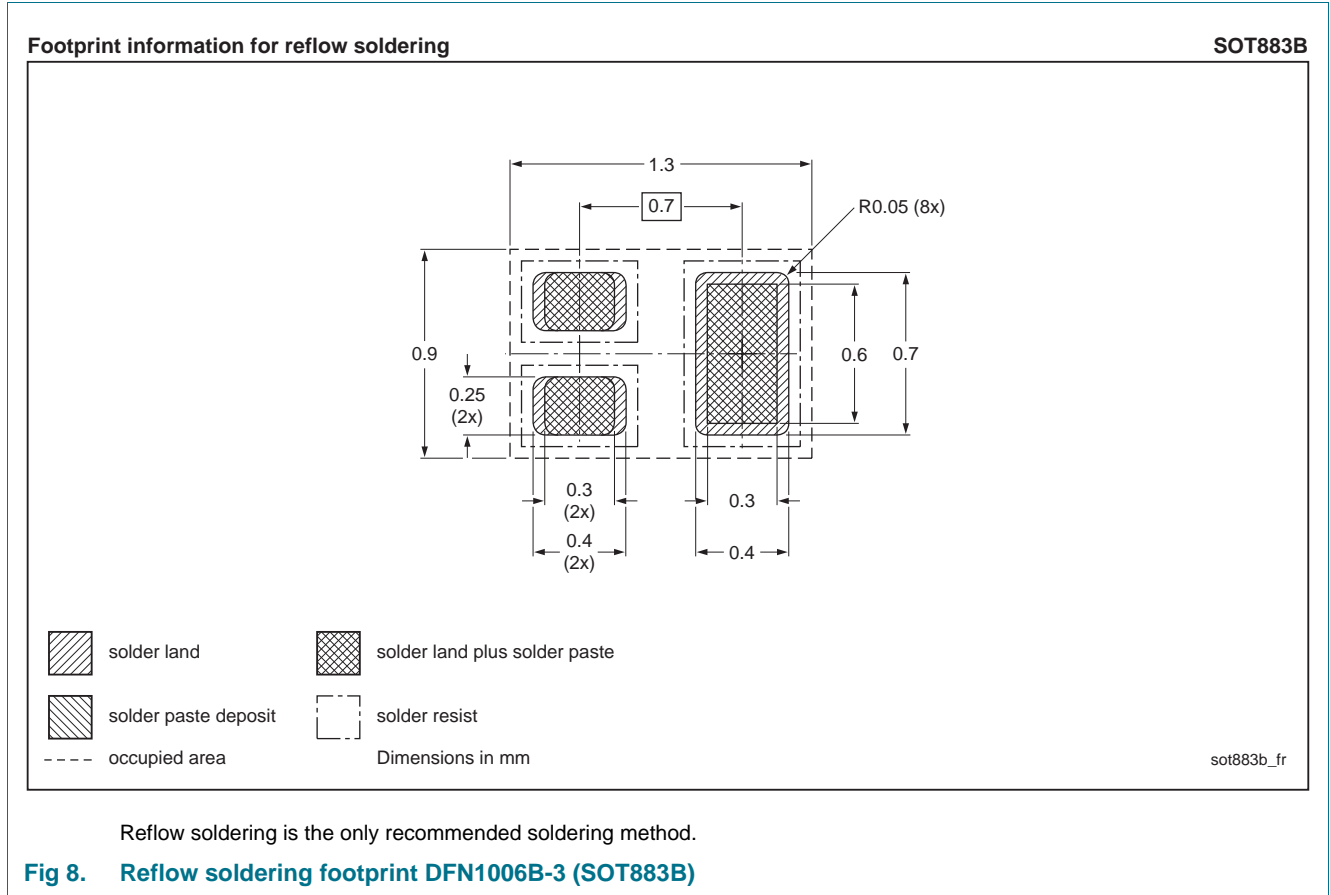
**Table 9. Packing methods**

The indicated -xxx are the last three digits of the 12NC ordering code.<sup>[1]</sup>

| Type number       | Package              | Description                    | Packing quantity |
|-------------------|----------------------|--------------------------------|------------------|
|                   |                      |                                | <b>10000</b>     |
| 2PA1774xMB series | DFN1006B-3 (SOT883B) | 2 mm pitch, 8 mm tape and reel | -315             |

[1] For further information and the availability of packing methods, see [Section 14](#).

11. Soldering





## 12. Revision history

**Table 10. Revision history**

| Document ID        | Release date | Data sheet status  | Change notice | Supersedes |
|--------------------|--------------|--------------------|---------------|------------|
| 2PA1774XMB_SER v.1 | 20120323     | Product data sheet | -             | -          |

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### 13.1 Data sheet status

| Document status <sup>[1][2]</sup> | Product status <sup>[3]</sup> | Definition  |
|-----------------------------------|-------------------------------|---|
| Objective [short] data sheet      | Development                   | This document contains data from the objective specification for product development. |
| Preliminary [short] data sheet    | Qualification                 | This document contains data from the preliminary specification.                       |
| Product [short] data sheet        | Production                    | This document contains the product specification.                                     |

[1] Please consult the most recently issued document before initiating or completing a design.

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Document identifier: 2PA1774XMB\_SER

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